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FAIRCHILD SEMICONDUCTOR®

Aug 2012

FDD8453LZ_F085

N-Channel Power Trench® MOSFET

40V, 50A, 6.5mΩ

Features

- Typ $r_{DS(on)}$ = 5mΩ at V_{GS} = 10V, I_D = 15A
- Typ $r_{DS(on)}$ = 6mΩ at V_{GS} = 4.5V, I_D = 13A
- HBM ESD protection level > 7kv typical
- RoHS Compliant
- Qualified to AEC Q101

General Description

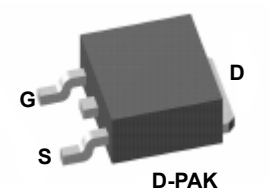
This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench® process that has been especially tailored to minimize the on-state resistance and switching loss. G-S zener has been added to enhance ESD voltage level.

Applications

- Inverter
- Synchronous Rectifier

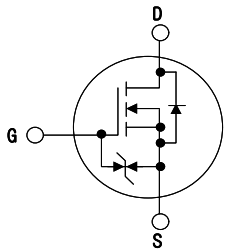
100% RoHS COMPLIANT

Package



D-PAK
(TO-252)

Symbol



MOSFET Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{DSS}	Drain to Source Voltage	40	V
V_{GS}	Gate to Source Voltage	±20	V
I_D	Drain Current - Continuous (Package limited) T_C = 25°C	50	A
	-Pulsed	Figure4	
E_{AS}	Single Pulse Avalanche Energy (Note 1)	88	mJ
P_D	Power Dissipation	118	W
	Dreate above 25°C	0.79	W/°C
T_J, T_{STG}	Operating and Storage Temperature	-55 to + 175	°C

Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance Junction to Case	1.27	°C/W
$R_{\theta JA}$	Thermal Resistance Junction to Ambient, 1in^2 copper pad area	52	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDD8453LZ	FDD8453LZ_F085	D-PAK(TO-252)	13”	12mm	2500 units

Electrical Characteristics T_C = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
Off Characteristics						
B_{VDSS}	Drain to Source Breakdown Voltage	I_D = 250μA, V_{GS} = 0V	40	-	-	V
I_{DSS}	Zero Gate Voltage Drain Current	V_{DS} = 32V, V_{GS} = 0V	-	-	1	μA
		V_{GS} = 0V, T_C = 150°C	-	-	250	
I_{GSS}	Gate to Source Leakage Current	V_{GS} = ±20V	-	-	±10	uA
On Characteristics						
$V_{GS(th)}$	Gate to Source Threshold Voltage	V_{GS} = V_{DS}, I_D = 250μA	1.0	1.8	3.0	V
$r_{DS(on)}$	Drain to Source On Resistance	I_D = 15A, V_{GS}= 10V	-	5.0	6.5	mΩ
		I_D = 13A, V_{GS}= 4.5V	-	6.0	7.8	mΩ
		I_D = 15A, V_{GS}= 10V T_J=175°C	-	9.4	12.2	mΩ
g_{FS}	Forward Transconductance	V_{DS} = 5V, I_D = 15A	-	91	-	S
Dynamic Characteristics						
C_{iss}	Input Capacitance	V_{DS} = 20V, V_{GS} = 0V, f = 1MHz	-	2935	-	pF
C_{oss}	Output Capacitance		-	340	-	pF
C_{rss}	Reverse Transfer Capacitance		-	260	-	pF
R_g	Gate Resistance	f = 1MHz	-	1.8	-	Ω
$Q_{g(ToT)}$	Total Gate Charge at 10V	V_{GS} = 0 to 10V, V_{DD} = 20V, I_D = 15A, I_g=1mA	-	60	78	nC
$Q_{g(5)}$	Total Gate Charge at 5V	V_{GS} = 0 to 5V, V_{DD} = 20V, I_D = 15A, I_g=1mA	-	32	42	nC
Q_{gs}	Gate to Source Gate Charge	V_{DD} = 20V, I_D = 15A, I_g=1mA	-	7.5	-	nC
Q_{gd}	Gate to Drain “Miller“ Charge	V_{DD} = 20V, I_D = 15A, I_g=1mA	-	13	-	nC

Electrical Characteristics T_C = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
Switching Characteristics						
t_{on}	Turn-On Time	V_{DD} = 20V, I_D = 15A, V_{GS} = 10V, R_{GEN} = 6Ω	-	-	34	ns
$t_{d(on)}$	Turn-On Delay Time		-	12	-	ns
t_r	Rise Time		-	10	-	ns
$t_{d(off)}$	Turn-Off Delay Time		-	43	-	ns
t_f	Fall Time		-	7	-	ns
t_{off}	Turn-Off Time		-	-	80	ns
Drain-Source Diode Characteristics						
V_{SD}	Source to Drain Diode Voltage	I_{SD} = 2A	-	0.7	1.2	V
		I_{SD} = 15A	-	0.8	1.3	V
t_{rr}	Reverse Recovery Time	I_F = 15A, dI_{SD}/dt = 100A/μs	-	25	33	ns
Q_{rr}	Reverse Recovery Charge		-	14	19	nC

Notes:

1: Starting T_J = 25°C, L = 0.11mH, I_{AS} = 40A, V_{DD} = 36V during inductor charging and V_{DD} = 0V during the time in Avalanche.

This product has been designed to meet the extreme test conditions and environment demanded by the automotive industry. For a copy of the requirements, see AEC Q101 at: http://www.aecouncil.com/
All Fairchild Semiconductor products are manufactured, assembled and tested under ISO9000 and QS9000 quality systems certification.

Typical Characteristics

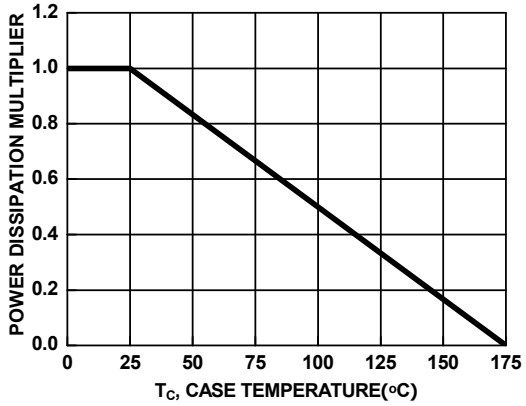


Figure 1. Normalized Power Dissipation vs Case Temperature

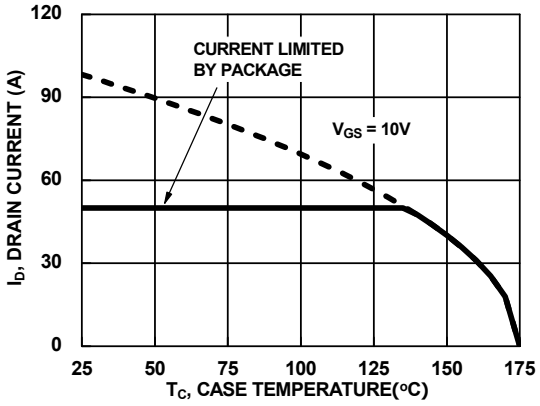


Figure 2. Maximum Continuous Drain Current vs Case Temperature

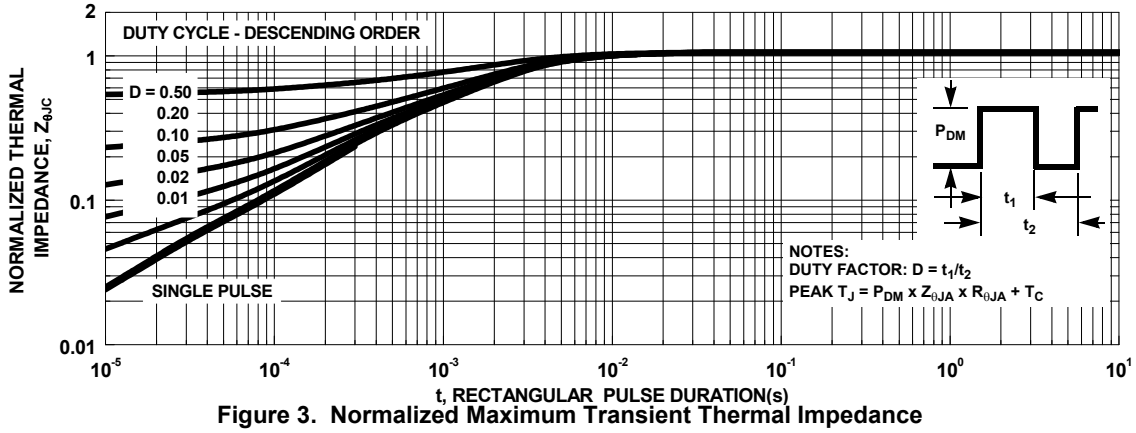


Figure 3. Normalized Maximum Transient Thermal Impedance

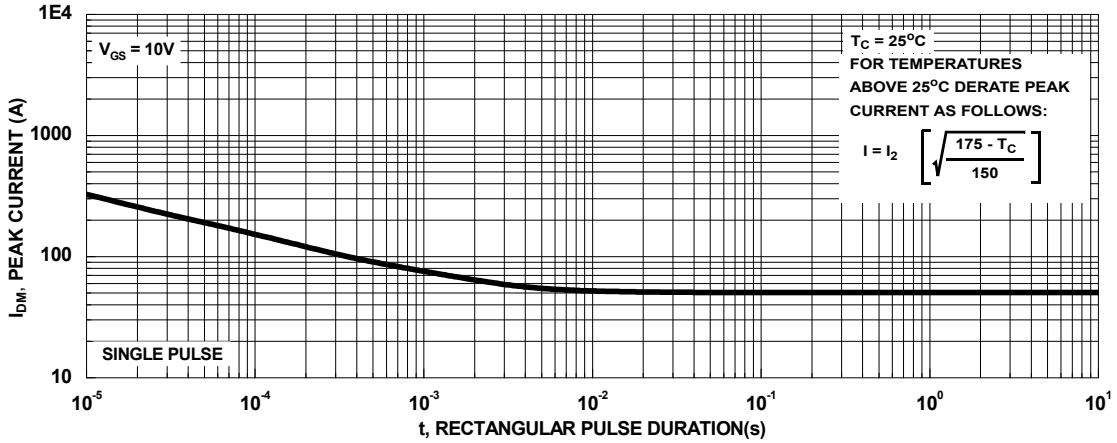


Figure 4. Peak Current Capability

Typical Characteristics

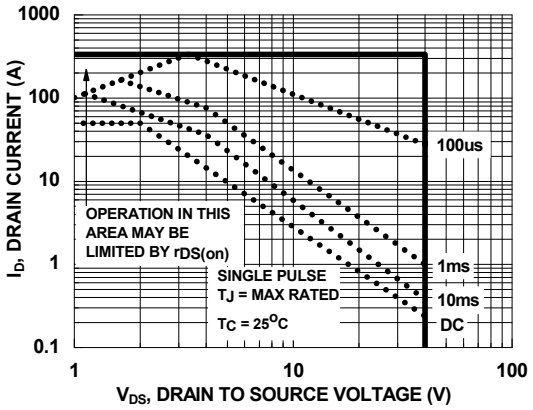
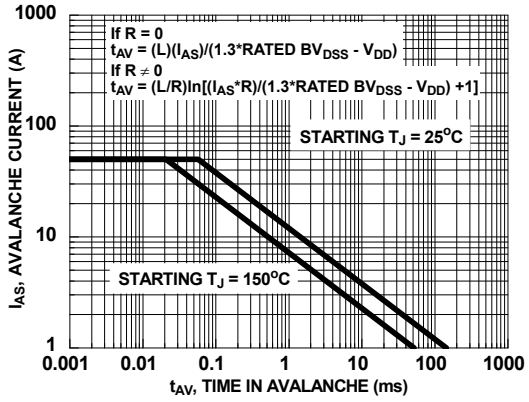


Figure 5. Forward Bias Safe Operating Area



NOTE: Refer to Fairchild Application Notes AN7514 and AN7515

Figure 6. Unclamped Inductive Switching Capability

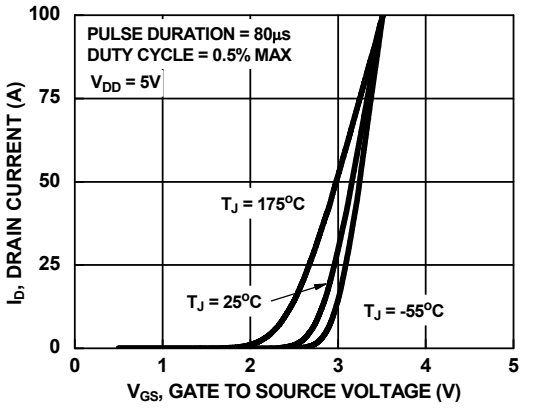


Figure 7. Transfer Characteristics

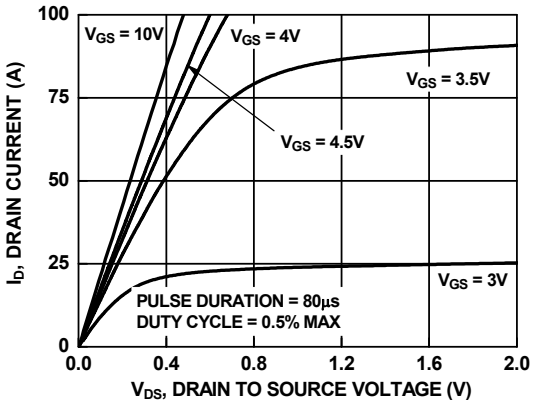


Figure 8. Saturation Characteristics

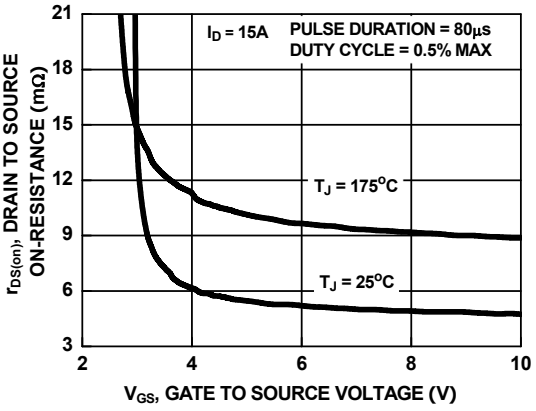


Figure 9. Drain to Source On-Resistance Variation vs Gate to Source Voltage

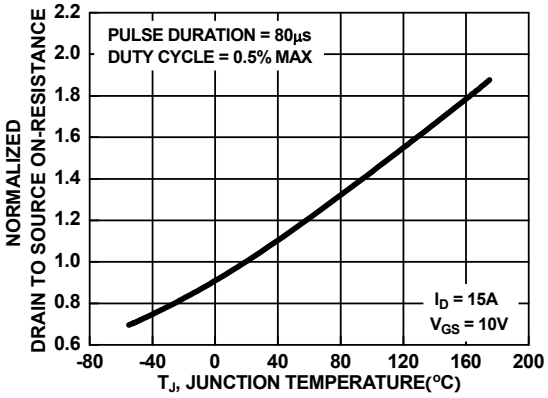


Figure 10. Normalized Drain to Source On Resistance vs Junction Temperature

Typical Characteristics

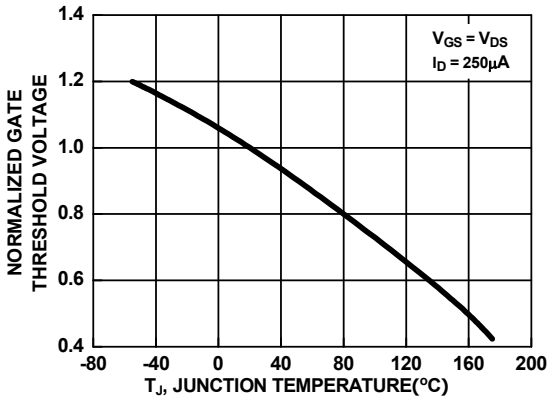


Figure 11. Normalized Gate Threshold Voltage vs Junction Temperature

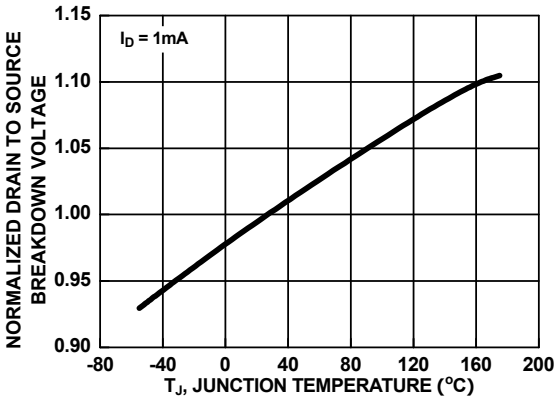


Figure 12. Normalized Drain to Source Breakdown Voltage vs Junction Temperature

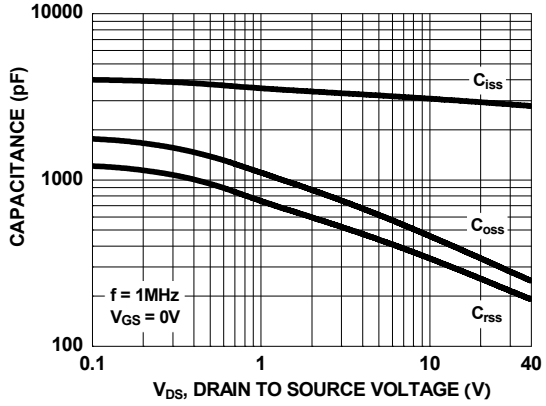


Figure 13. Capacitance vs Drain to Source Voltage

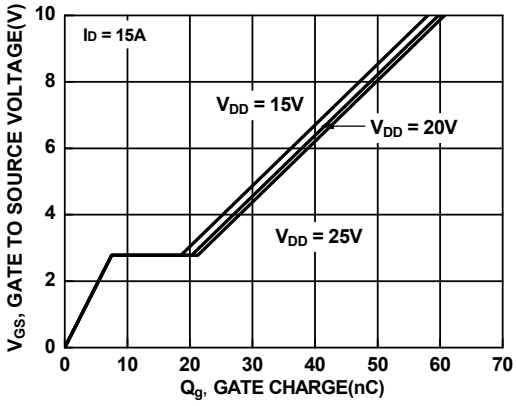


Figure 14. Gate Charge vs Gate to Source Voltage

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Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
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Rev. I55

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FDD8453LZ_F085

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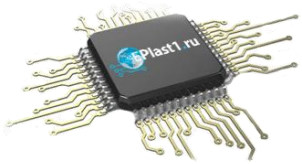
- Защита от снятия компонента с производства.



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